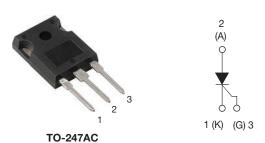


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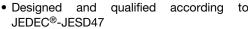
Vishay Semiconductors

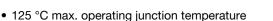
# Thyristor High Voltage, Phase Control SCR, 30 A

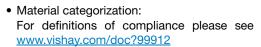


| PRODUCT SUMMARY    |                  |  |  |  |  |  |  |  |  |
|--------------------|------------------|--|--|--|--|--|--|--|--|
| Package            | TO-247AC         |  |  |  |  |  |  |  |  |
| Diode variation    | Single SCR       |  |  |  |  |  |  |  |  |
| I <sub>T(AV)</sub> | 20 A             |  |  |  |  |  |  |  |  |
| $V_{DRM}/V_{RRM}$  | 800 V, 1200 V    |  |  |  |  |  |  |  |  |
| $V_{TM}$           | 1.3 V            |  |  |  |  |  |  |  |  |
| I <sub>GT</sub>    | 45 mA            |  |  |  |  |  |  |  |  |
| $T_J$              | -40 °C to 125 °C |  |  |  |  |  |  |  |  |

### **FEATURES**













### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

### **DESCRIPTION**

The VS-30TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

| MAJOR RATINGS AND CHARACTERISTICS  |                              |             |       |  |  |  |  |  |  |
|------------------------------------|------------------------------|-------------|-------|--|--|--|--|--|--|
| PARAMETER                          | TEST CONDITIONS              | VALUES      | UNITS |  |  |  |  |  |  |
| I <sub>T(AV)</sub>                 | Sinusoidal waveform          | 20          | ^     |  |  |  |  |  |  |
| I <sub>RMS</sub>                   |                              | 30          | _ A   |  |  |  |  |  |  |
| V <sub>RRM</sub> /V <sub>DRM</sub> |                              | 800/1200    | V     |  |  |  |  |  |  |
| I <sub>TSM</sub>                   |                              | 300         | A     |  |  |  |  |  |  |
| V <sub>T</sub>                     | 20 A, T <sub>J</sub> = 25 °C | 1.3         | V     |  |  |  |  |  |  |
| dV/dt                              |                              | 500         | V/µs  |  |  |  |  |  |  |
| dl/dt                              |                              | 150         | A/μs  |  |  |  |  |  |  |
| T <sub>J</sub>                     |                              | - 40 to 125 | °C    |  |  |  |  |  |  |

| VOLTAGE RATINGS              |   |   |   |  |  |  |  |  |  |
|------------------------------|---|---|---|--|--|--|--|--|--|
| PART NUMBER                  | V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM<br>REPETITIVE PEAK AND<br>OFF-STATE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM<br>NON-REPETITIVE PEAK<br>REVERSE VOLTAGE<br>V | I <sub>RRM</sub> /I <sub>DRM</sub><br>AT 125 °C<br>mA |  |  |  |  |  |  |
| VS-30TPS08PbF, VS-30TPS08-M3 | 800   | 900   | 10  |  |  |  |  |  |  |
| VS-30TPS12PbF, VS-30TPS12-M3 | 1200  | 1300  | 10  |  |  |  |  |  |  |



| ABSOLUTE MAXIMUM RATINGS                   |                                  |  |  |       |                  |  |  |  |  |
|--|----------------------------------|--|--|-------|------------------|--|--|--|--|
| PARAMETER                                  | SYMBOL                           | TEST CO  | VALUES   | UNITS |                  |  |  |  |  |
| Maximum average on-state current           | I <sub>T(AV)</sub>               | T <sub>C</sub> = 95 °C, 180° conduction                                | half sine wave                                   | 20    |                  |  |  |  |  |
| Maximum RMS on-state current               | I <sub>RMS</sub>                 |  |  | 30    | ۸                |  |  |  |  |
| Maximum peak, one-cycle                    |                                  | 10 ms sine pulse, rated V <sub>RRN</sub>                               | <sub>d</sub> applied                             | 250   | Α                |  |  |  |  |
| non-repetitive surge current               | I <sub>TSM</sub>                 | 10 ms sine pulse, no voltage   | reapplied  | 300   |                  |  |  |  |  |
| Maximum 12t for fusion                     | l <sup>2</sup> t                 | 10 ms sine pulse, rated V <sub>RRN</sub>                               | <sub>d</sub> applied                             | 310   | A <sup>2</sup> s |  |  |  |  |
| Maximum I <sup>2</sup> t for fusing        | 1-1                              | 10 ms sine pulse, no voltage   | 442  | A-S   |                  |  |  |  |  |
| Maximum I <sup>2</sup> √t for fusing       | I <sup>2</sup> √t                | t = 0.1 to 10 ms, no voltage r   | 4420   | A²√s  |                  |  |  |  |  |
| Maximum on-state voltage drop              | V <sub>TM</sub>                  | 20 A, T <sub>J</sub> = 25 °C   |  |       | V                |  |  |  |  |
| On-state slope resistance                  | r <sub>t</sub>                   |  |  | 12    | mΩ               |  |  |  |  |
| Threshold voltage                          | V <sub>T(TO)</sub>               | T <sub>J</sub> = 125 °C  |  | 1.0   | V                |  |  |  |  |
| Manipulation and dispatch along a summer   | 1 //                             | T <sub>J</sub> = 25 °C   | V Datady A                                       | 0.5   |                  |  |  |  |  |
| Maximum reverse and direct leakage current | I <sub>RM</sub> /I <sub>DM</sub> | T <sub>J</sub> = 125 °C  | $V_R$ = Rated $V_{RRM}/V_{DRM}$                  | 10    | A                |  |  |  |  |
| Maximum holding current                    | I <sub>H</sub>                   | Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 °C |  | 150   | mA               |  |  |  |  |
| Maximum latching current                   | ΙL                               | Anode supply = 6 V, resistive load, T <sub>J</sub> = 25 °C             |  | 200   |                  |  |  |  |  |
| Maximum rate of rise of off-state voltage  | dV/dt                            | $T_J = T_J$ maximum, linear to 8                                       | 30 % V <sub>DRM</sub> , R <sub>g</sub> -k = Open | 500   | V/µs             |  |  |  |  |
| Maximum rate of rise of turned-on current  | dI/dt                            |  |  | 150   | A/μs             |  |  |  |  |

| TRIGGERING                                  |                    |  |        |       |  |  |  |  |
|---|--------------------|--|--------|-------|--|--|--|--|
| PARAMETER                                   | SYMBOL             | TEST CONDITIONS  | VALUES | UNITS |  |  |  |  |
| Maximum peak gate power                     | P <sub>GM</sub>    |  | 8.0    | W     |  |  |  |  |
| Maximum average gate power                  | P <sub>G(AV)</sub> |  | 2.0    | VV    |  |  |  |  |
| Maximum peak positive gate current          | + I <sub>GM</sub>  |  | 1.5    | Α     |  |  |  |  |
| Maximum peak negative gate voltage          | - V <sub>GM</sub>  |  | 10     | V     |  |  |  |  |
|   |                    | Anode supply = 6 V, resistive load, $T_J$ = - 10 °C              | 60     |       |  |  |  |  |
| Maximum required DC gate current to trigger | I <sub>GT</sub>    | Anode supply = 6 V, resistive load, $T_J = 25  ^{\circ}\text{C}$ | 45     | mA    |  |  |  |  |
|   |                    | Anode supply = 6 V, resistive load, T <sub>J</sub> = 125 °C      | 20     |       |  |  |  |  |
|   |                    | Anode supply = 6 V, resistive load, T <sub>J</sub> = - 10 °C     | 2.5    |       |  |  |  |  |
| Maximum required DC gate voltage to trigger | $V_{GT}$           | Anode supply = 6 V, resistive load, $T_J = 25  ^{\circ}\text{C}$ | 2.0    | V     |  |  |  |  |
| voltage to anggor                           |                    | Anode supply = 6 V, resistive load, $T_J$ = 125 °C               | 1.0    | V     |  |  |  |  |
| Maximum DC gate voltage not to trigger      | $V_{GD}$           | T. 405 00 V. Puladada  |        |       |  |  |  |  |
| Maximum DC gate current not to trigger      | I <sub>GD</sub>    | T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = Rated value          | 2.0    | mA    |  |  |  |  |

| SWITCHING                     |                 |                              |        |       |  |  |  |  |
|-------------------------------|-----------------|------------------------------|--------|-------|--|--|--|--|
| PARAMETER                     | SYMBOL          | TEST CONDITIONS              | VALUES | UNITS |  |  |  |  |
| Typical turn-on time          | t <sub>gt</sub> | T <sub>J</sub> = 25 °C       | 0.9    |       |  |  |  |  |
| Typical reverse recovery time | t <sub>rr</sub> | T _ 105 °C                   | 4      | μs    |  |  |  |  |
| Typical turn-off time         | t <sub>q</sub>  | $T_J = 125 ^{\circ}\text{C}$ | 110    |       |  |  |  |  |

| THERMAL AND MECHANICAL SPECIFICATIONS           |         |                                   |                                      |            |            |  |  |  |
|---|---------|-----------------------------------|--------------------------------------|------------|------------|--|--|--|
| PARAMETER                                       |         | SYMBOL TEST CONDITIONS            |                                      | VALUES     | UNITS      |  |  |  |
| Maximum junction and storage temperature range  |         | T <sub>J</sub> , T <sub>Stg</sub> |                                      | -40 to 125 | °C         |  |  |  |
| Maximum thermal resistance, junction to case    |         | $R_{thJC}$                        | DC operation                         | 0.8        |            |  |  |  |
| Maximum thermal resistance, junction to ambient |         | R <sub>thJA</sub>                 | DC operation                         | 40         | °C/W       |  |  |  |
| Maximum thermal resistance, case to heatsink    |         | R <sub>thCS</sub>                 | Mounting surface, smooth and greased | 0.2        |            |  |  |  |
| Approximate weight                              |         |                                   |                                      | 6          | g          |  |  |  |
| Approximate weight                              |         |                                   |                                      | 0.21       | OZ.        |  |  |  |
| Mounting torque                                 | minimum |                                   |                                      | 6 (5)      | kgf ⋅ cm   |  |  |  |
| Mounting torque -                               | maximum |                                   |                                      | 12 (10)    | (lbf ⋅ in) |  |  |  |
| Marking daving                                  |         |                                   | Coop of the TO 247AC (IEDEC)         | 30TI       | PS08       |  |  |  |
| Marking device                                  |         |                                   | Case style TO-247AC (JEDEC)          | 30TI       | PS12       |  |  |  |

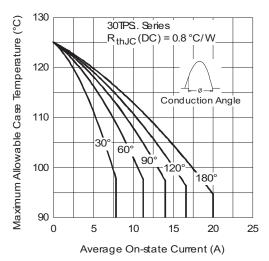


Fig. 1 - Current Rating Characteristics

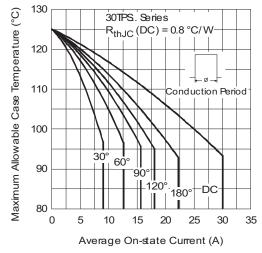


Fig. 2 - Current Rating Characteristics

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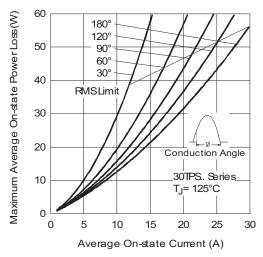


Fig. 3 - On-State Power Loss Characteristics

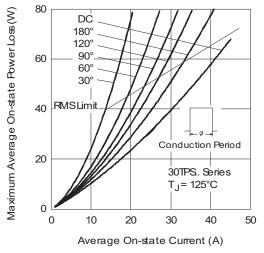


Fig. 4 - On-State Power Loss Characteristics

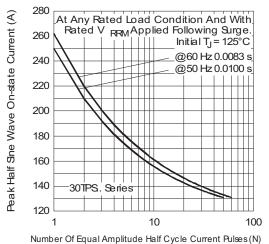


Fig. 5 - Maximum Non-Repetitive Surge Current

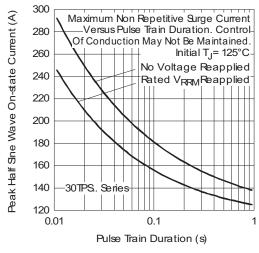


Fig. 6 - Maximum Non-Repetitive Surge Current

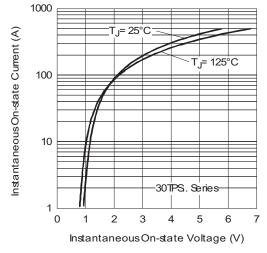


Fig. 7 - On-State Voltage Drop Characteristics

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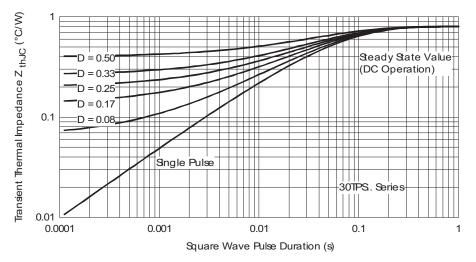


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

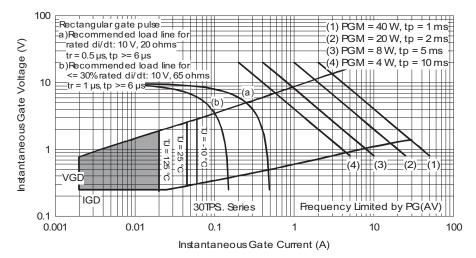
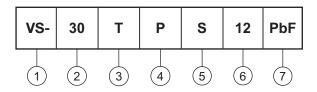


Fig. 9 - Gate Characteristics

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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

Circuit configuration:

T = Thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage code x 100 = V<sub>RRM</sub> - 08 = 800 V 12 = 1200 V

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) |                  |                        |                          |  |  |  |  |  |  |  |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |  |  |  |  |  |
| VS-30TPS08PbF                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |  |
| VS-30TPS08-M3                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |  |
| VS-30TPS12PbF                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |  |
| VS-30TPS12-M3                  | 25               | 500                    | Antistatic plastic tubes |  |  |  |  |  |  |  |

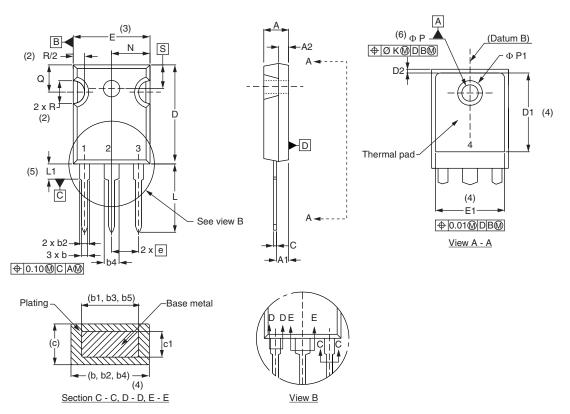
| LINKS TO RELATED DOCUMENTS |              |                          |  |  |  |  |  |  |
|----------------------------|--------------|--------------------------|--|--|--|--|--|--|
| Dimensions                 |              | www.vishay.com/doc?95542 |  |  |  |  |  |  |
| Part marking information   | TO-247AC PbF | www.vishay.com/doc?95226 |  |  |  |  |  |  |
|                            | TO-247AC -M3 | www.vishay.com/doc?95007 |  |  |  |  |  |  |



### Vishay Semiconductors

### **TO-247**

### **DIMENSIONS** in millimeters and inches



| SYMBOL   | MILLIMETERS |       | INC   | HES   | NOTES | IOTES | SYMBOL  | MILLIN   | IETERS | INC   | HES   | NOTES |
|----------|-------------|-------|-------|-------|-------|-------|---------|----------|--------|-------|-------|-------|
| STIVIBOL | MIN.        | MAX.  | MIN.  | MAX.  | NOTES |       | STWIBOL | MIN.     | MAX.   | MIN.  | MAX.  | NOTES |
| Α        | 4.65        | 5.31  | 0.183 | 0.209 |       |       | D2      | 0.51     | 1.30   | 0.020 | 0.051 |       |
| A1       | 2.21        | 2.59  | 0.087 | 0.102 |       |       | Е       | 15.29    | 15.87  | 0.602 | 0.625 | 3     |
| A2       | 1.50        | 2.49  | 0.059 | 0.098 |       |       | E1      | 13.72    | -      | 0.540 | -     |       |
| b        | 0.99        | 1.40  | 0.039 | 0.055 |       |       | е       | 5.46     | BSC    | 0.215 | BSC   |       |
| b1       | 0.99        | 1.35  | 0.039 | 0.053 |       |       | ØΚ      | 2.       | 54     | 0.0   | )10   |       |
| b2       | 1.65        | 2.39  | 0.065 | 0.094 |       |       | L       | 14.20    | 16.10  | 0.559 | 0.634 |       |
| b3       | 1.65        | 2.34  | 0.065 | 0.092 |       |       | L1      | 3.71     | 4.29   | 0.146 | 0.169 |       |
| b4       | 2.59        | 3.43  | 0.102 | 0.135 |       |       | Ν       | 7.62 BSC |        | 0     | .3    |       |
| b5       | 2.59        | 3.38  | 0.102 | 0.133 |       |       | ØΡ      | 3.56     | 3.66   | 0.14  | 0.144 |       |
| С        | 0.38        | 0.89  | 0.015 | 0.035 |       |       | Ø P1    | -        | 6.98   | -     | 0.275 |       |
| c1       | 0.38        | 0.84  | 0.015 | 0.033 |       |       | Q       | 5.31     | 5.69   | 0.209 | 0.224 |       |
| D        | 19.71       | 20.70 | 0.776 | 0.815 | 3     |       | R       | 4.52     | 5.49   | 0.178 | 0.216 |       |
| D1       | 13.08       | -     | 0.515 | -     | 4     |       | S       | 5.51     | BSC    | 0.217 | BSC   |       |

#### Notes

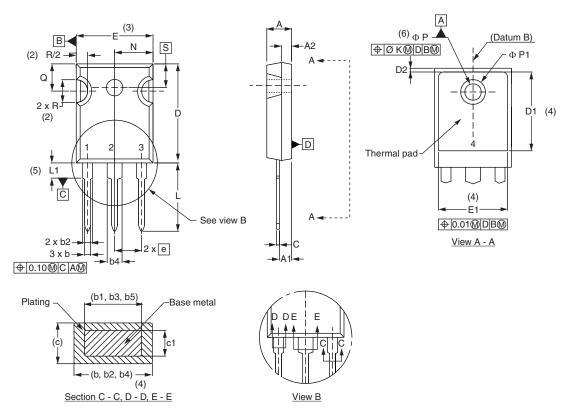
- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}\,$  Outline conforms to JEDEC® outline TO-247 with exception of dimension c



Vishay Semiconductors

### TO-247 - 50 mils L/F

### **DIMENSIONS** in millimeters and inches



| SYMBOL  | MILLIMETERS |       | INC   | INCHES |       | NOTES | SYMBOL  | MILLIM | IETERS | INC   | HES   | NOTES |
|---------|-------------|-------|-------|--------|-------|-------|---------|--------|--------|-------|-------|-------|
| STIMBOL | MIN.        | MAX.  | MIN.  | MAX.   | NOTES | NOTES | STWIBOL | MIN.   | MAX.   | MIN.  | MAX.  | NOTES |
| Α       | 4.65        | 5.31  | 0.183 | 0.209  |       |       | D2      | 0.51   | 1.35   | 0.020 | 0.053 |       |
| A1      | 2.21        | 2.59  | 0.087 | 0.102  |       |       | E       | 15.29  | 15.87  | 0.602 | 0.625 | 3     |
| A2      | 1.17        | 1.37  | 0.046 | 0.054  |       |       | E1      | 13.46  | -      | 0.53  | -     |       |
| b       | 0.99        | 1.40  | 0.039 | 0.055  |       |       | е       | 5.46   | BSC    | 0.215 | BSC   |       |
| b1      | 0.99        | 1.35  | 0.039 | 0.053  |       |       | ØK      | 0.2    | 254    | 0.0   | 10    |       |
| b2      | 1.65        | 2.39  | 0.065 | 0.094  |       |       | L       | 14.20  | 16.10  | 0.559 | 0.634 |       |
| b3      | 1.65        | 2.34  | 0.065 | 0.092  |       |       | L1      | 3.71   | 4.29   | 0.146 | 0.169 |       |
| b4      | 2.59        | 3.43  | 0.102 | 0.135  |       |       | N       | 7.62   | BSC    | 0     | .3    |       |
| b5      | 2.59        | 3.38  | 0.102 | 0.133  |       |       | ØΡ      | 3.56   | 3.66   | 0.14  | 0.144 |       |
| С       | 0.38        | 0.89  | 0.015 | 0.035  |       |       | Ø P1    | ı      | 7.39   | -     | 0.291 |       |
| c1      | 0.38        | 0.84  | 0.015 | 0.033  |       |       | Q       | 5.31   | 5.69   | 0.209 | 0.224 |       |
| D       | 19.71       | 20.70 | 0.776 | 0.815  | 3     |       | R       | 4.52   | 5.49   | 0.178 | 0.216 |       |
| D1      | 13.08       | -     | 0.515 | -      | 4     |       | S       | 5.51   | BSC    | 0.217 | BSC   |       |

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$  Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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Vishay

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000